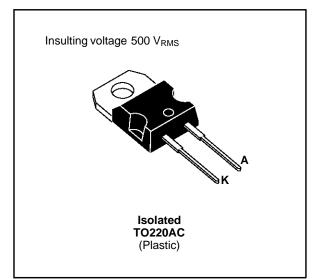


BYT 08PI-1000

FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED: Capacitance 7pF



SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter	Value	Unit	
Vrrm	Repetitive Peak Reverse Voltage	1000	V	
V _{RSM}	Non Repetitive Peak Reverse Voltage	petitive Peak Reverse Voltage		
I _{FRM}	Repetitive Peak Forward Current	t _p ≤ 10μs	100	А
I _{F (RMS)}	RMS Forward Current		16	А
IF (AV)	Average Forward Current	$\begin{array}{l} T_{c}=80^{\circ}C\\ \delta=0.5 \end{array}$	8	A
I _{FSM}	Surge Non Repetitive Forward Current	t _p = 10ms Sinusoidal	50	A
Р	Power Dissipation	$T_c = 80^{\circ}C$	17	W
T _{stg} Tj	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	°C

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j - c)}	Junction-case	4	°C/W

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I _R	$T_j = 25^{\circ}C$	$V_R = V_{RRM}$			35	μA
	$T_j = 100^{\circ}C$				2	mA
VF	T _j = 25°C	I _F = 8A			1.9	V
	T _j = 100°C				1.8	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions					Тур.	Max.	Unit
t _{rr}	$T_j = 25^{\circ}C$	I _F = 1A	di _F /dt = - 15A/µs	$V_R = 30V$			155	ns
		I _F = 0.5A	I _R = 1A	$I_{rr} = 0.25A$			65	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions		Min.	Тур.	Max.	Unit
t _{IRM}	di⊧/dt = - 32A/µs	V _{CC} = 200 V I _F = 8A			200	ns
	di _F /dt = - 64A/µs	L _p ≤ 0.05μH T _j = 100°C See Figure 1		120		
I _{RM}	di _F /dt = - 32A/µs				5.5	А
	di _F /dt = - 64A/µs			6		

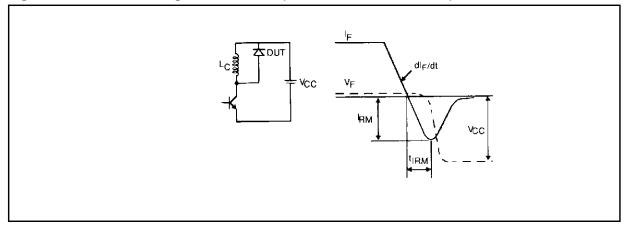
TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Condition s				Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	T _j = 100°C d _{iF} /dt = - 8A/μs	$V_{CC} = 200V$ $L_p = 2\mu H$	$I_F = I_{F (AV)}$ See figure 2			4.5	

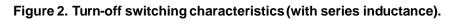
To evaluate the conduction losses use the following equation:

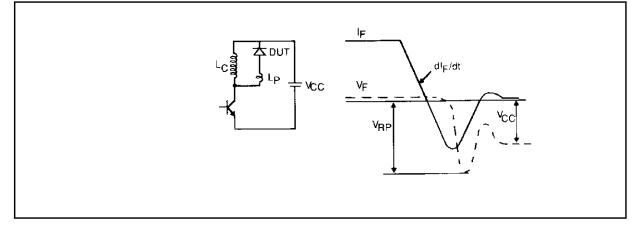
 $V_F = 1.47 + 0.04 I_F$ $P = 1.47 \times I_{F(AV)} + 0.04 I_{F}^{2}(RMS)$





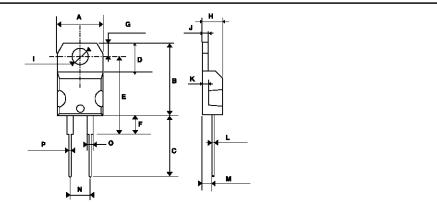








PACKAGE MECHANICAL DATA : TO220AC Plastic



	DIMENSIONS					
REF.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
А	10.0	10.4	0.393	0.409		
В	15.2	15.9	0.598	0.626		
С	13	14	0.511	0.551		
D	6.2	6.6••••	0.244	0.260		
E	16.4 typ.		0.645 typ.			
F	3.5	4.2	0.137	0.165		
G	2.65	2.95	0.104	0.116		
Н	4.4	4.6	0.173	0.181		
I	3.75	3.85	0.147	0.151		
J	1.23	1.32	0.048	0.051		
К	1.27 typ.		0.050 typ.			
L	0.49	0.70	0.019	0.027		
М	2.4	2.72	0.094	0.107		
N	4.95	5.15	0.194	0.203		
0	1.14	1.70	0.044	0.067		
Р	0.61	0.88	0.024	0.034		

Cooling method: by conduction (method C) Marking: type number Weight: 2.1g Recommended torque value: 80cm. N Maximum torque value: 100cm. N

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